

TISP4160LP, TISP4180LP SYMMETRICAL TRANSIENT VOLTAGE SUPPRESSORS

APRIL 1987 - REVISED SEPTEMBER 1997

absolute maximum ratings at 25°C case temperature (unless otherwise noted)

RATING	SYMBOL	VALUE	UNIT
Non-repetitive peak on-state pulse current (see Notes 1, 2 and 3) 8/20 μ s (ANSI C62.41, open-circuit voltage wave shape 1.2/50 μ s) 5/200 μ s (VDE 0433, open-circuit voltage wave shape 2 kV, 10/700 μ s) 0.2/310 μ s (RLM 88, open-circuit voltage wave shape 1.5 kV, 0.5/700 μ s) 5/310 μ s (CCITT IX K17, open-circuit voltage wave shape 1.5 kV, 10/700 μ s)	I_{TSP}	100 50 38 38	A
Non-repetitive peak on-state current, 50 Hz, 1 s (see Notes 1 and 2)	I_{TSM}	2.5	A rms
Initial rate of rise of on-state current, Linear current ramp, Maximum ramp value < 38 A	di_T/dt	250	A/ μ s
Junction temperature	T_J	150	°C
Operating free - air temperature range		0 to 70	°C
Storage temperature range	T_{stg}	-40 to +150	°C
Lead temperature 1.5 mm from case for 10 s	T_{lead}	260	°C

- NOTES: 1. Above 70°C, derate linearly to zero at 150°C case temperature
 2. This value applies when the initial case temperature is at (or below) 70°C. The surge may be repeated after the device has returned to thermal equilibrium.
 3. Most PTT's quote an unloaded voltage waveform. In operation the TISP essentially shorts the generator output. The resulting loaded current waveform is specified.

electrical characteristics, $T_J = 25^\circ\text{C}$

PARAMETER	TEST CONDITIONS	TISP4160			TISP4180			UNIT
		MIN	TYP	MAX	MIN	TYP	MAX	
V_Z Reference zener voltage	$I_Z = \pm 1\text{mA}$	± 120			± 145			V
αV_Z Temperature coefficient of reference voltage			0.1			0.1		%/°C
$V_{(BO)}$ Breakover voltage	(see Notes 4 and 5)			± 160			± 180	V
$I_{(BO)}$ Breakover current	(see Note 4)	± 0.15		± 0.6	± 0.15		± 0.6	A
V_{TM} Peak on-state voltage	$I_T = \pm 5\text{A}$ (see Notes 4 and 5)		± 2.2	± 3		± 2.2	± 3	V
I_H Holding current	(see Note 4)	± 150			± 150			mA
dv/dt Critical rate of rise of off-state voltage	(see Note 6)			± 5			± 5	kV/ μ s
I_D Off-state leakage current	$V_D = \pm 50\text{V}$			± 10			± 10	μ A
C_{off} Off-state capacitance	$V_D = 0$ $f = 1\text{kHz}$		70	150		70	150	pF

- NOTES: 4. These parameters must be measured using pulse techniques, $t_w = 100\ \mu\text{s}$, duty cycle $\leq 2\%$.
 5. These parameters are measured with voltage sensing contacts separate from the current carrying contacts located within 3.2 mm (0.125 inch) from the device body.
 6. Linear rate of rise, maximum voltage limited to 80 % V_Z (minimum).

thermal characteristics

PARAMETER	MIN	TYP	MAX	UNIT
$R_{\theta JA}$ Junction to free air thermal resistance			156	°C/W

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VOLTAGE SUPPRESSORS**

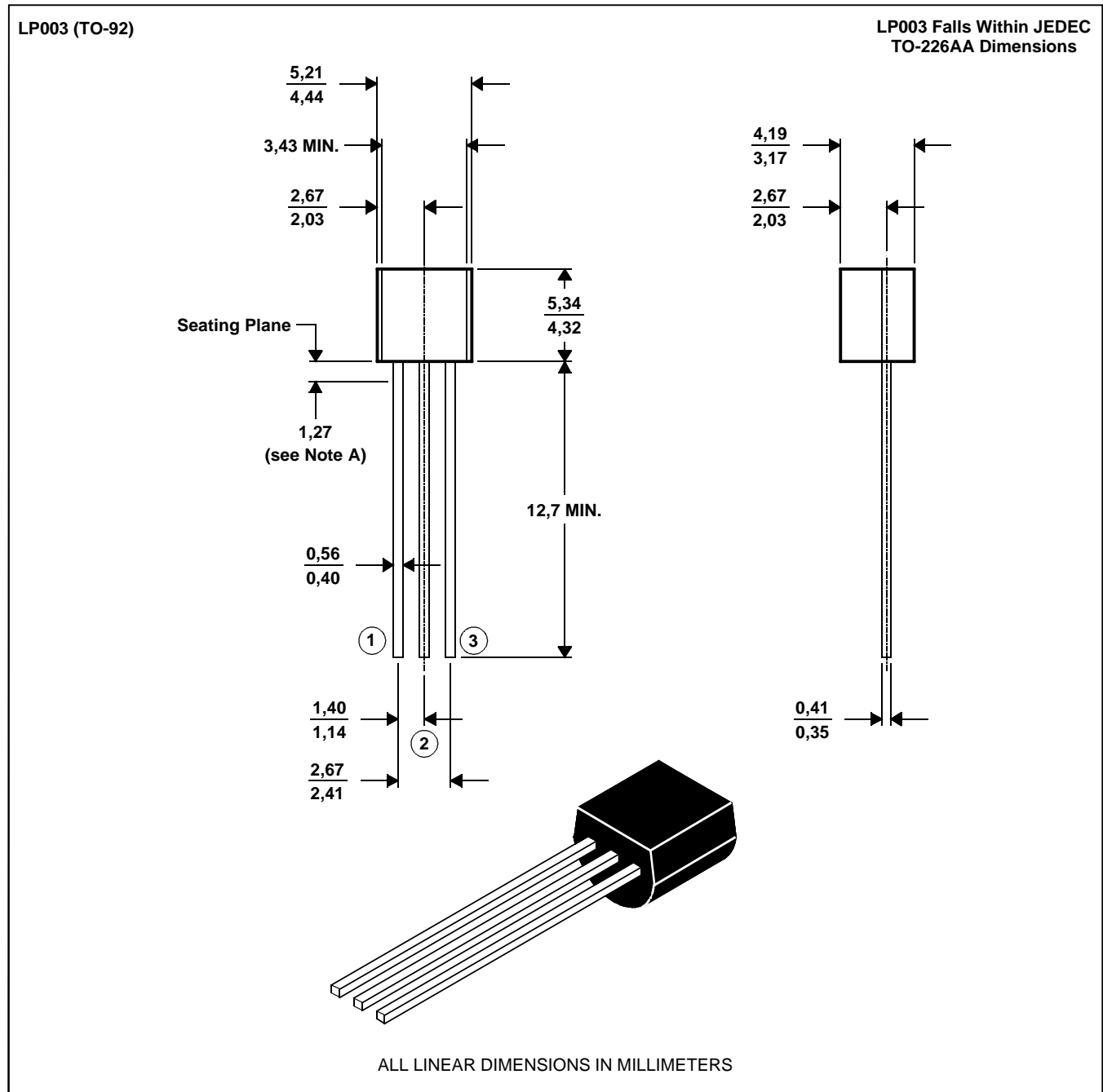
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MECHANICAL DATA

LP003 (TO-92)

3-pin cylindrical plastic package

This single-in-line package consists of a circuit mounted on a lead frame and encapsulated within a plastic compound. The compound will withstand soldering temperature with no deformation, and circuit performance characteristics will remain stable when operated in high humidity conditions. Leads require no additional cleaning or processing when used in soldered assembly.



NOTE A: Lead dimensions are not controlled in this area.

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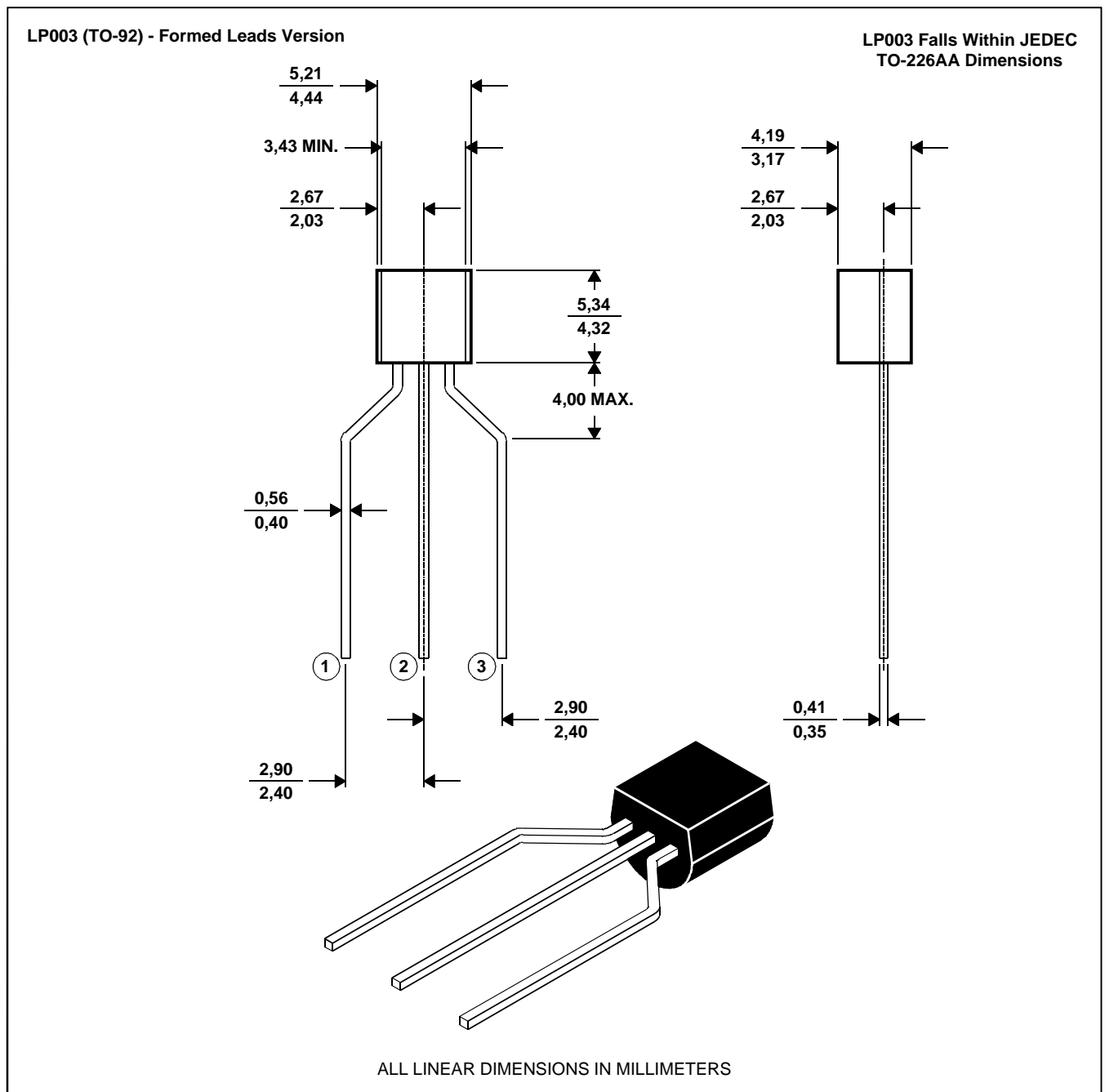
PRODUCT INFORMATION

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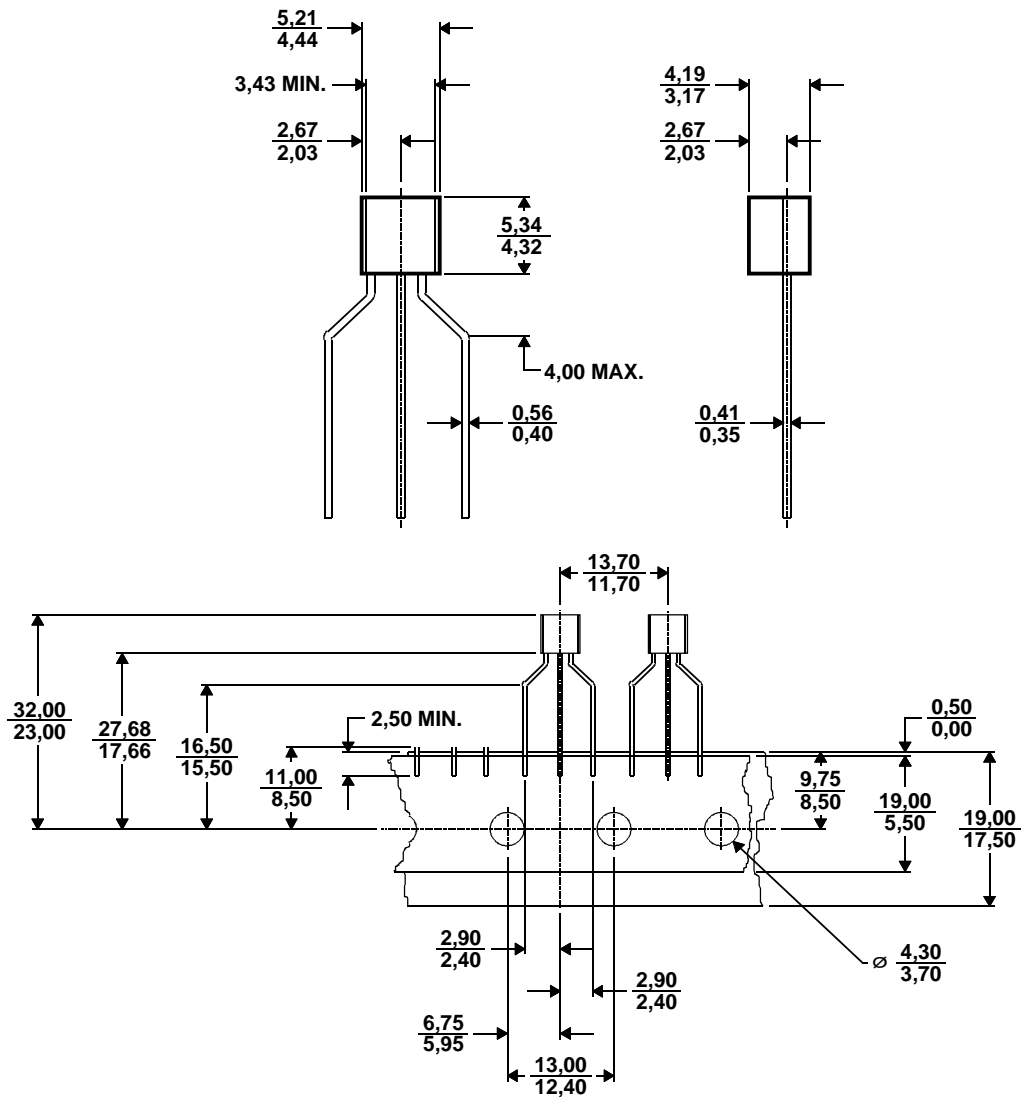
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MECHANICAL DATA

LPR

tape dimensions

LP Package (TO-92) Tape (Formed Lead Version)



ALL LINEAR DIMENSIONS IN MILLIMETERS

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